EM74LVC07A

Hex buffer with open-drain outputs

Product datasheet, Rev. 1.1 Dec 15, 2025

1.General Description

The 74LVC07A is a hex buffer with open-drain outputs. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2.Features and Benefits

- Wide supply voltage range from 1.2 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- CMOS low power dissipation
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - HBM ANSI/ESDA/JEDEC JS-001 Class 3A exceeds 6000 V
  - CDM ANSI/ESDA/JEDEC JS-002 Class C3 exceeds 2000 V
- Multiple package options

3.Ordering Information

Table 1. Ordering information

Type number	Topside marking	Package		
		Name	Description	Quantity
EM74LVC07AD	LVC07A XYYWW	SOP-14L	plastic small outline package; 14 leads; body width 3.9 mm	3000
EM74LVC07APW	LVC07A XYYWW	TSSOP-14L	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	3000

MARKING INFORMATION

NOTE: XYYWW = Vendor Code and Date Code.

X YY WW

Date Code -Week

Date Code -Year

Vendor Number

4.Function Diagram

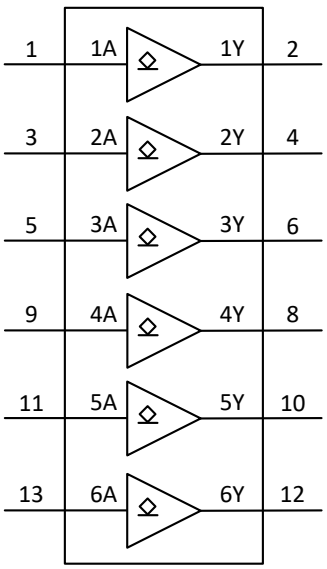


Fig. 1. Logic symbol

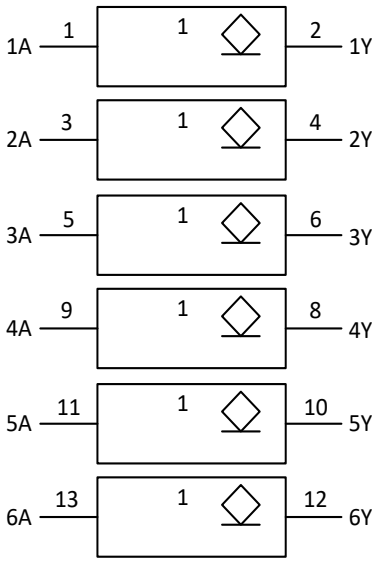


Fig. 2. IEC logic symbol

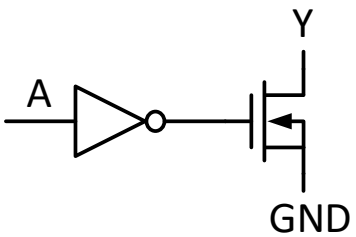


Fig. 3. Logic diagram (one gate)

5.Pinning Information

5.1. Pinning

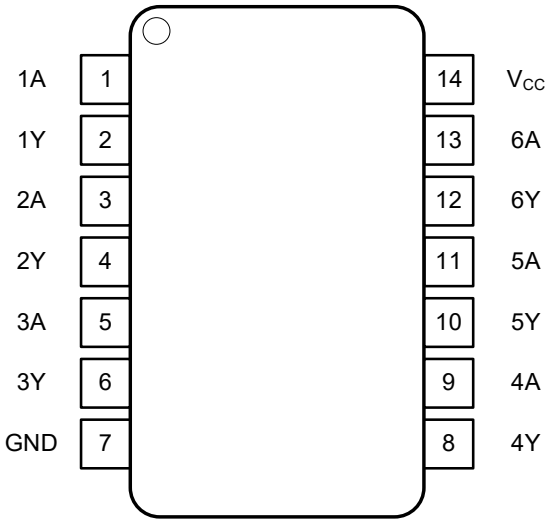


Fig. 4. Top view pin configuration SOP and TSSOP

5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1A, 2A, 3A, 4A, 5A, 6A	1, 3, 5, 9, 11, 13	Data input
1Y, 2Y, 3Y, 4Y, 5Y, 6Y	2, 4, 6, 8, 10, 12	Data output
GND	7	Ground (0V)
V_{CC}	14	Supply voltage

6.Functional Description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

Input nA	Output nY
L	L
H	Z

7. Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Table 4. Absolute Maximum Ratings

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND.

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	6.5	V
I_{IK}	input clamping current	$V_I < 0$ V	-50		mA
V_I	input voltage	[1]	-0.5	6.5	V
I_{OK}	output clamping current	$V_O < 0$ V	-50		mA
V_O	output voltage	Active mode [1]	-0.5	6.5	V
		Power-down mode; Vcc = 0 V [1]	-0.5	6.5	V
I_O	output current	V_O = 0 V to V_{CC}		50	mA
I_{CC}	supply current			100	mA
I_{GND}	ground current		-100		mA
P_{tot}	total power dissipation	T_{amb} = -40 °C to + 125 °C		500	mW
T_{stg}	storage temperature		-65	150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. EnergyMath does not recommend exceeding them or designing to Absolute Maximum Ratings.

Table 5. Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.65	5.5	V
		functional	1.2		V
V_I	input voltage		0	5.5	V
V_O	output voltage	Active mode	0	5.5	V
		Power-down mode; Vcc = 0 V	0	5.5	V
T_{amb}	ambient temperature		-40	125	°C
Δt/ΔV	input transition rise and fall rate	V_{CC} = 1.65 V to 2.7 V	0	20	ns/V
		V_{CC} = 2.7 V to 3.6 V	0	10	ns/V
		V_{CC} = 4.5 V to 5.5 V	0	5	ns/V

9.Static Characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V_{CC} = 1.2 V	1.08			1.08		V
		V_{CC} = 1.65 V to 1.95 V	0.65V_{CC}			0.65V_{CC}		V
		V_{CC} = 2.3 V to 2.7 V	1.7			1.7		V
		V_{CC} = 2.7 V to 3.6 V	2.0			2.0		V
		V_{CC} = 4.5 V to 5.5 V	0.7V_{CC}			0.7V_{CC}		V
V_{IL}	LOW-level input voltage	V_{CC} = 1.2 V			0.12		0.12	V
		V_{CC} = 1.65 V to 1.95 V			0.35V_{CC}		0.35V_{CC}	V
		V_{CC} = 2.3 V to 2.7 V			0.7		0.7	V
		V_{CC} = 2.7 V to 3.6 V			0.8		0.8	V
		V_{CC} = 4.5 V to 5.5 V			0.3V_{CC}		0.3V_{CC}	V
V_{OL}	LOW-level output voltage	V_I = V_{IH} or V_{IL}						
		I_O = 100µA; V_{CC} = 1.65 V to 5.5 V			0.10		0.10	V
		I_O = 4 mA; V_{CC} = 1.65 V			0.45		0.70	V
		I_O = 8 mA; V_{CC} = 2.3 V			0.30		0.45	V
		I_O = 12 mA; V_{CC} = 2.7 V			0.40		0.60	V
		I_O = 24 mA; V_{CC} = 3.0 V			0.55		0.80	V
		I_O = 32 mA; V_{CC} = 4.5 V			0.55		0.80	V
I_I	input leakage current	V_I = 5.5 V or GND ; V_{CC} = 0 V to 5.5 V		±0.1	±5		±20	µA
I_{OZ}	OFF-state output current	V_I = V_{IH}; V_O = 5.5 V or GND; V_{CC} = 1.65 V to 5.5 V		±0.1	±10		±20	µA
I_{OFF}	power-off leakage current	V_{CC} = 0 V; V_I or V_O = 5.5 V		±0.1	±10		±20	µA
I_{CC}	supply current	V_{CC} = 1.65 V to 5.5 V ; V_I = V_{CC} or GND ; I_O = 0 A ;		0.01	10		40	µA

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
ΔI_{CC}	additional supply current	per input pin ; V_{CC} = 2.3 V to 5.5 V ; $V_I = V_{CC}$ - 0.6 V ; I_O = 0 A		0.2	500		5000	µA
C_I	input capacitance	V_{CC} = 3.3 V ; V_I = GND to V_{CC}		4				pF

[1]All typical values are measured at V_{CC} = 3.3V and T_{amb} = 25 °C.

10. Dynamic Characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
t_{PZL}	OFF-state to LOW propagation delay	nA to nY; see Fig. 5						
		V_{CC} = 1.2 V		28.3				ns
		V_{CC} = 1.65 V to 1.95 V	3.5	8.5	16.5	3.5	17	ns
		V_{CC} = 2.3 V to 2.7 V	2.0	4.8	8.0	2.0	9.0	ns
		V_{CC} = 3.0 V to 3.6 V	1.5	3.5	5.5	1.5	6.0	ns
		V_{CC} = 4.5 V to 5.5 V	1.0	2.9	4.5	1.0	5.0	ns
t_{PLZ}	LOW to OFF-state propagation delay	nA to nY; see Fig. 5						
		V_{CC} = 1.2 V		25.3				ns
		V_{CC} = 1.65 V to 1.95 V	3.5	7.7	14.5	3.5	15	ns
		V_{CC} = 2.3 V to 2.7 V	2.0	5.0	7.5	2.0	8.0	ns
		V_{CC} = 3.0 V to 3.6 V	1.5	3.5	5.5	1.5	6.0	ns
		V_{CC} = 4.5 V to 5.5 V	1.0	2.4	3.5	1.0	4.0	ns
C_{PD}	power dissipation capacitance	per buffer ; V_I = GND to V_{CC} [2]						
		V_{CC} = 1.65 V to 1.95 V		3.3				pF
		V_{CC} = 2.3 V to 2.7 V		3.4				pF
		V_{CC} = 3.0 V to 3.6 V		3.9				pF
		V_{CC} = 4.5 V to 5.5 V		4.8				pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.2 V, 1.8 V, 2.5 V, 3.3 V and 5.0 V respectively.

[2] C_{PD} is used to determine the dynamic power dissipation (P_D in µW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

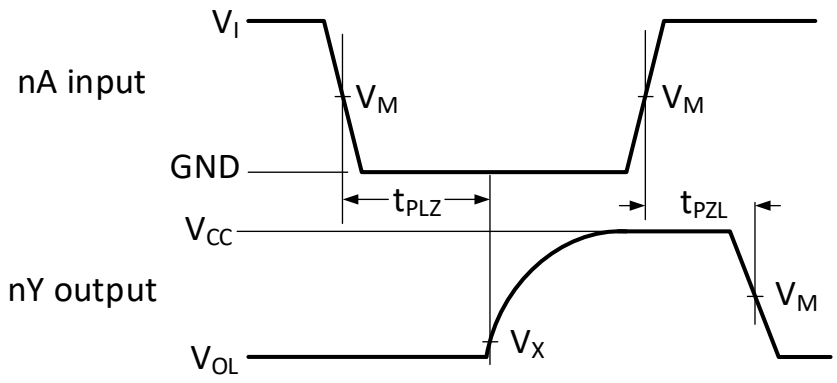
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

10.1. Waveforms and test circuit



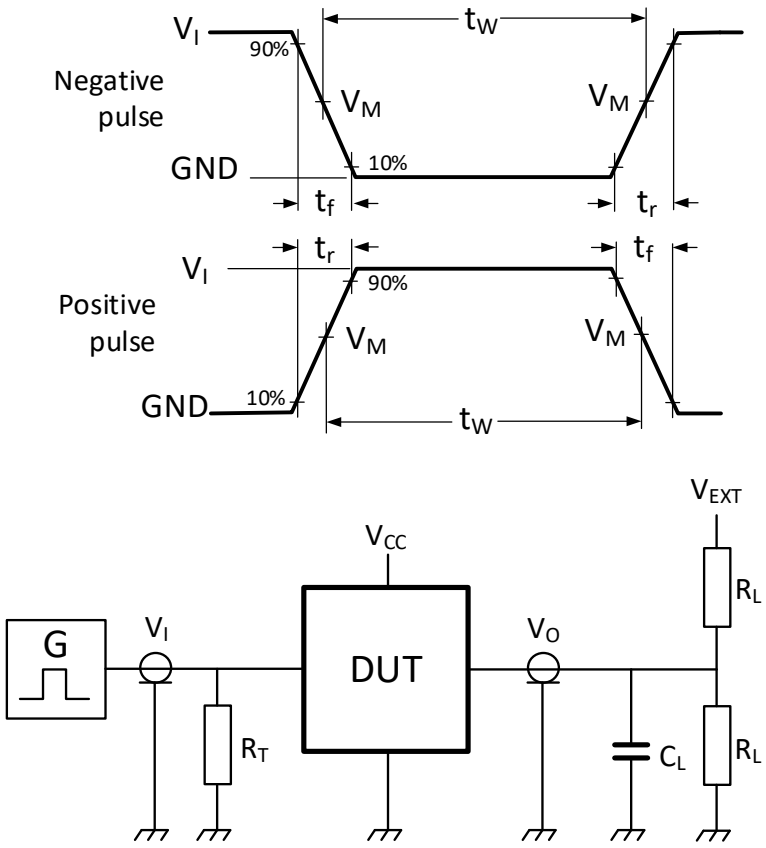
Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 5. The input nA to output nY propagation delays

Table 8. Measurement points

Supply voltage	Input	Output	
V_{CC}	V_M	V_X	V_M
1.2 V	$0.5V_{CC}$	V_{OL} + 0.15 V	$0.5V_{CC}$
1.65 V to 1.95 V	$0.5V_{CC}$	V_{OL} + 0.15 V	$0.5V_{CC}$
2.3 V to 2.7 V	$0.5V_{CC}$	V_{OL} + 0.15 V	$0.5V_{CC}$
3.0 V to 3.6 V	1.5 V	V_{OL} + 0.3 V	1.5 V
4.5 V to 5.5 V	$0.5V_{CC}$	V_{OL} + 0.3 V	$0.5V_{CC}$



Test data is given in Table 9.
Definitions for test circuit:
R_L = Load resistance.
C_L = Load capacitance including jig and probe capacitance.
R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.
V_{EXT} = External voltage for measuring switching times.

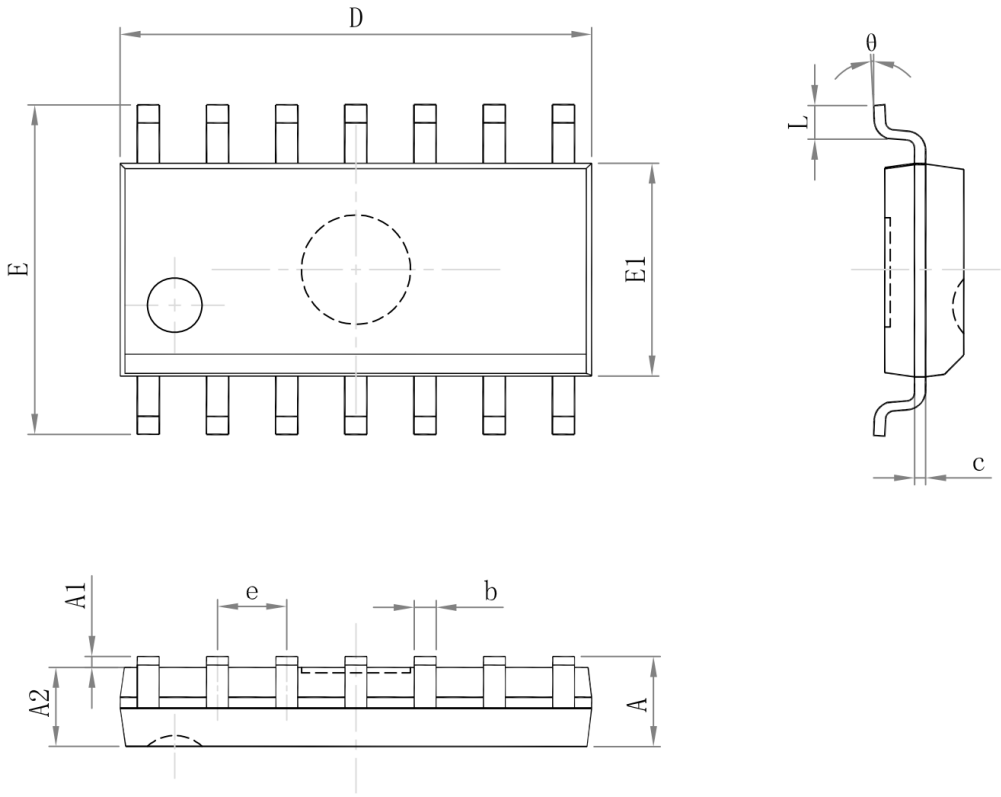
Fig. 6. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLZ}, t_{PZL}
1.2V	V_{CC}	≤ 2.0 ns	15 pF	500 Ω	2 x V_{CC}
1.65 V to 1.95 V	V_{CC}	≤ 2.0 ns	15 pF	500 Ω	2 x V_{CC}
2.3 V to 2.7 V	V_{CC}	≤ 2.0 ns	15 pF	500 Ω	2 x V_{CC}
3.0 V to 3.6 V	3 V	≤ 2.0 ns	15 pF	500 Ω	6.0 V
4.5 V to 5.5 V	V_{CC}	≤ 2.0 ns	15 pF	500 Ω	2 x V_{CC}

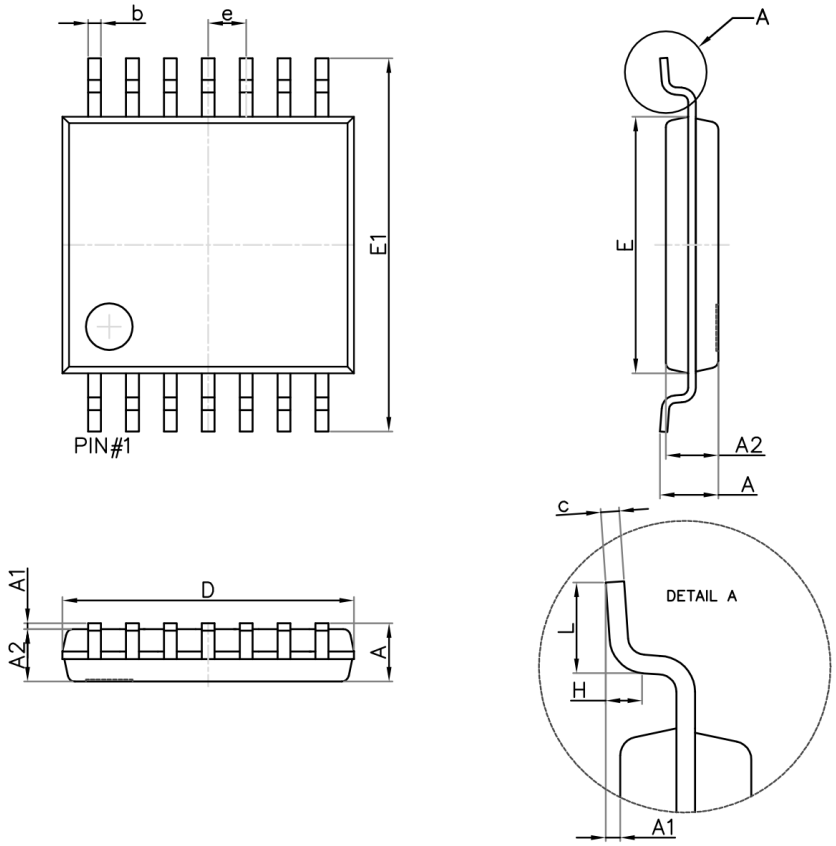
11. Package Outline

SOP-14L



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	——	1.75
A1	0.05	0.25
A2	1.25	1.60
b	0.31	0.51
c	0.10	0.25
D	8.45	8.85
e	1.27(BSC)	
E	5.80	6.20
E1	3.80	4.00
L	0.40	1.27
θ	0°	8°

TSSOP-14L



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	——	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
e	0.65(BSC)	
E1	6.20	6.60
E	4.30	4.50
L	0.45	0.75
θ	0°	8°

12. Tape and Reel Information

12.1. Carrier tape dimensions

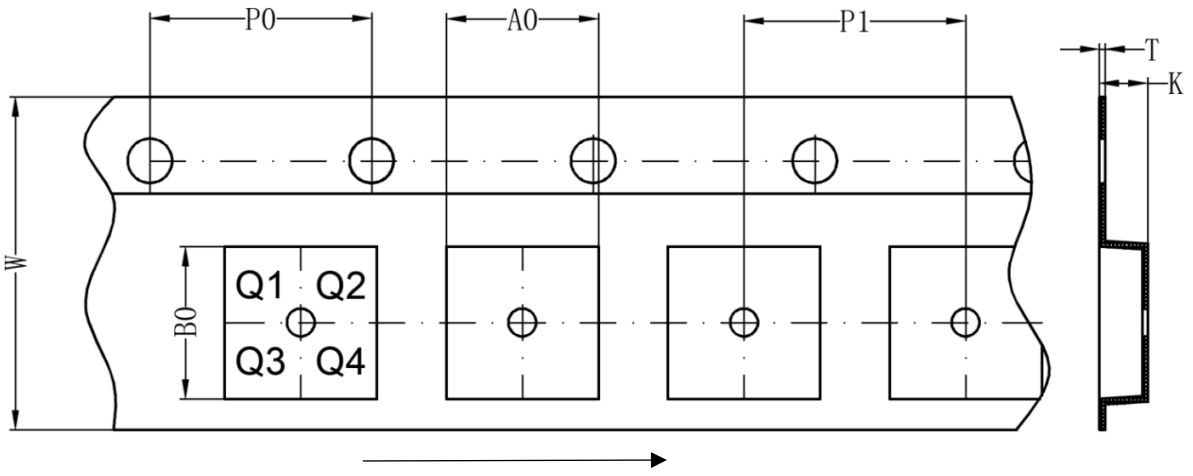


Table 10. Carrier tape dimensions

Package version	A0(mm)	B0(mm)	K0(mm)	T(mm)	P1(mm)	W(mm)	P0(mm)	PIN 1
SOP-14L	6.35	9.1	1.9	0.22	8	16	4	Q1
TSSOP-14L	6.7	5.45	1.6	0.25	8	12	4	Q1

12.2. Reel and box dimensions

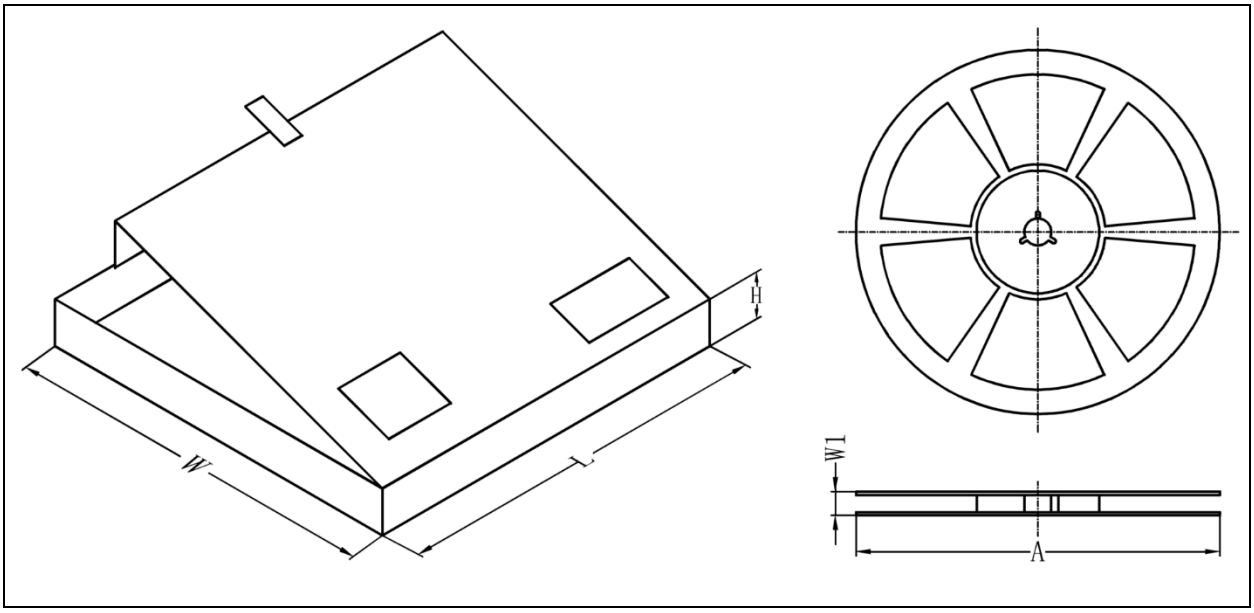


Table 11. Dimensions and quantities

Package version	Type NO. ending	Reel Dimension A (mm)	Reel Width W1 (mm)	MPQ (pcs)	Reels per box	Outer box dimensions L×W×H(mm)
SOP-14L	D	330	22.4	3000	1	358x340x50
TSSOP-14L	PW	330	18.4	3000	1	358x340x50

13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
CDM	Charged Device Model
TTL	Transistor-Transistor Logic

14. Revision History

Table 13. Revision history

Document ID	Release Date	Data sheet status	Change notice	Supersedes
EM74LVC07A Rev. 1.1	Dec 15, 2025	Product datasheet		EM74LVC07A Rev. 1.0
Modifications:	• Table 1: added topside marking information. • Table 5 updated. • Section 12: added tape and reel information.			
EM74LVC07A Rev1.0	Oct 30, 2023	Product datasheet		